

09/891,552

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,787,861 B2
DATED : September 7, 2004
INVENTOR(S) : Lucovsky et al.

Page 1 of 1

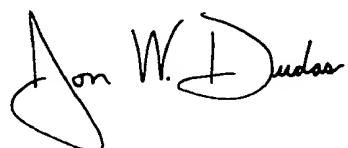
It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 12.

Line 4, should read -- **15**. The field effect transistor according to claim 3, --
Line 9, should read -- **16**. The field effect transistor according to claim 3, --
Line 13, should read -- **17**. The field effect transistor according to claim 3, --

Signed and Sealed this

First Day of February, 2005



JON W. DUDAS
Director of the United States Patent and Trademark Office